

Surface Mount PIN Diodes

Technical Data

HSMP-38XX and HSMP-48XX Series

Features

- Diodes Optimized for:
 Low Current Switching
 Low Distortion Attenuating
 Ultra-Low Distortion
 Switching
 Microwave Frequency
 Operation
- Surface Mount SOT-23 and SOT-143 Packages
 Single and Dual Versions
 Tape and Reel Options
 Available
- Low Failure in Time (FIT)
 Rate^[1]

Note:

 For more information see the Surface Mount PIN Reliability Data Sheet.

Description/Applications

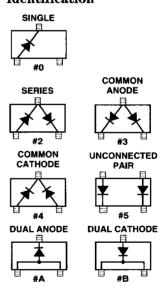
The HSMP-380X and HSMP-381X series are specifically designed for low distortion attenuator applications. The HSMP-382X series is optimized for switching applications where ultra-low resistance is required. The HSMP-3880 switching diode is an ultra low distortion device optimized for higher power applications from 50 MHz to 1.5 GHz. The HSMP-389X series is optimized for switching applications where low resistance at low current and low capacitance are

required. The HSMP-48XX series are special products featuring ultra low parasitic inductance in the SOT-23 package, specifically designed for use at frequencies which are much higher than the upper limit for conventional SOT-23 PIN diodes. The HSMP-4810 diode is a low distortion attenuating PIN designed for operation to 3 GHz. The HSMP-4820 diode is ideal for limiting and low inductance switching applications up to 1.5 GHz. The HSMP-4890 is optimized for low current switching applications up to 3 GHz.

The HSMP-386X series of general purpose PIN diodes are designed for two classes of applications. The first is attenuators where current consumption is the most important design consideration. The second application for this series of diodes is in switches where low cost is the driving issue for the designer.

The HSMP-386X series Total Capacitance (C_T) and Total Resistance (R_T) are typical specifications. For applications that require guaranteed performance, the general purpose HSMP-383X series is recommended. For low distortion

Package Lead Code Identification



attenuators, the HSMP-380X or -381X series are recommended. For high performance switching applications, the HSMP-389X series is recommended.

A SPICE model is not available for PIN diodes as SPICE does not provide for a key PIN diode characteristic, carrier lifetime.

Absolute Maximum Ratings^[1] $T_A = 25^{\circ}C$

Symbol	Parameter	Units	Absolute Maximum
I _f	Forward Current (1 ms Pulse)	Amp	1
P _t	Total Device Dissipation	mW[2]	250
P _{iv}	Peak Inverse Voltage		Same as V _{BR}
T _j	Junction Temperature	°C	150
T_{STG}	Storage Temperature	°C	-65 to 150

Notes:

- Operation in excess of any one of these conditions may result in permanent damage to this device.
- 2. CW Power Dissipation at T_{LEAD} = 25°C. Derate to zero at maximum rated temperature.

PIN Attenuator Diodes Electrical Specifications $T_A = 25^{\circ}C$ (Each Diode)

Part Number HSMP-	Package Marking Code ^[1]	Lead Code	Configuration	Nearest Equivalent Axial Lead Part No. 5082-	Minimum Breakdown Voltage V _{BR} (V)	Maximum Series Resistance $R_S(\Omega)$	Maximum Total Capacitance C _T (pF)	Minimum High Resistance R _H (Ω)	$\begin{array}{c} \textbf{Maximum} \\ \textbf{Low} \\ \textbf{Resistance} \\ \textbf{R}_{\textbf{L}}\left(\Omega\right) \end{array}$
3800	D()	0	Single	3080	100	2.0	0.37	1000	8
3802	D2	2	Series						
3804	D4	4	Common Cathode						
3810	E0	0	Single	3081	100	3.0	0.35	1500	10
3812	E2	2	Series						
3813	E3	3	Common Anode				1		
3814	E4	4	Common Cathode						
Test Co	nditions				$V_R = V_{BR}$ Measure $I_R \le 10 \ \mu A$	I _F = 100 mA f = 100 MHz	$V_R = 50 \text{ V}$ $f = 1 \text{ MHz}$	I _F = 0.01 mA f = 100 MHz	

PIN Switching Diodes Electrical Specifications $T_A = 25^{\circ}C$

Part Number HSMP-	Package Marking Code ^[1]	Lead Code	Configuration	Nearest Equivalent Axial Lead Part No. 5082-	Minimum Breakdown Voltage V _{BR} (V)	Maximum Series Resistance $R_S(\Omega)$	Maximum Total Capacitance C _T (pF)	Maximum Shunt Mode Harmonic Distortion Hmd (dBc)
3820	F0	0	Single	3188	50	0.6*	0.8*	
3822	F2	2	Series	1				
3823	F3	3	Common Anode					
3824	F4	4	Common Cathode					
3880	S0	0	Single		100	6.5	0.40	~55
3890	G0	0	Single		100	2.5	0.30**	
3892	G2	2	Series					
3893	G3	3	Common Anode					
3894	G4	4	Common Cathode					
3895	G5	5	Unconnected Pair		_			
Test Co	nditions				$V_R = V_{BR}$ Measure $I_R \le 10 \mu\text{A}$	$I_F = 5 \text{ mA}$ $f = 100 \text{ MHz}$ $I_F = 10 \text{ mA*}$	$V_{R} = 50 \text{ V}$ $f = 1 \text{ MHz}$ $V_{R} = 20 \text{ V*}$ $V_{R} = 5 \text{ V**}$	$\begin{array}{c} 2 \; f_{o} \; Z_{o} = 50 \; W \\ f_{o} = 400 \; MHz \\ P_{in} = +30 \; dBm \\ 0 \; V \; bias \end{array}$

Note:

1. Package marking code is white.

PIN General Purpose Diodes, Electrical Specifications T_A = 25 $^{\circ}\mathrm{C}$

Part Number HSMP-	Package Marking Code ^[1]	Lead Code	Configuration	Nearest Equivalent Axial Lead Part No. 5082-	Minimum Breakdown Voltage V _{BR} (V)	$\begin{array}{c} \mathbf{Maximum} \\ \mathbf{Series} \\ \mathbf{Resistance} \\ \mathbf{R_S}\left(\Omega\right) \end{array}$	Maximum Total Capacitance C _T (pF)
3830	К0	0	Single	3077	200	1.5	0.3
3832	K2	2	Series				
3833	K3	3	Common Anode				
3834	K4	4	Common Cathode				
Test Co	nditions				$V_{\rm R} = V_{\rm BR}$ Measure $I_{\rm R} \le 10~{\rm mA}$	I _F = 100 mA f = 100 MHz	V _R = 50 V f = 1 MHz

High Frequency (Low Inductance, 500 MHz – 3 GHz) PIN Diodes, Electrical Specifications T_A = 25°C

Part Number HSMP-	Package Marking Code	Lead Code	Config- uration	Minimum Break- down Voltage V _{BR} (V)	$\begin{array}{c} \textbf{Maximum} \\ \textbf{Series} \\ \textbf{Resis-} \\ \textbf{tance} \\ \textbf{R}_{\textbf{S}}\left(\Omega\right) \end{array}$	Typical Total Capaci- tance C _T (pF)	Maximum Total Capacitance C _T (pF)	Typical Total Induc- tance L _{J'} (nH)	Appli- cation
4810	EB	В	Dual Cathode	100	3.0	0.35	0.4	1.0	Attenu- ator
4820	FA	A	Dual Anode	50	0.6*	0.75*	1.0	1.0*	Limiter
4890	GA	A	Dual Anode	100	2.5**	0.33	0.375	1.0	Switch
				$\begin{aligned} V_R &= V_{BR} \\ \text{Measure} \\ I_R &\leq 10 \ \mu\text{A} \end{aligned}$	$I_{\rm F} = 100 \text{ mA}$ $I_{\rm F} = 10 \text{ mA*}$ $I_{\rm F} = 5 \text{ mA**}$	$V_{R} = 50 \text{ V}$ $f = 1 \text{ MHz}$ $V_{R} = 20 \text{ V}^{\approx}$	$V_{R} = 50 \text{ V}$ $f = 1 \text{ MHz}$ $V_{R} = 0 \text{ V}$	f = 5.00 MHz - 5 GHz V _R = 20 V*	

PIN General Purpose Diodes, Typical Specifications $T_A = 25$ °C

Part Number HSMP-	Code Marking Code ^[1]	Lead Code	Configuration	Minimum Breakdown Voltage V _{BR} (V)	Typical Series Resistance $R_S(\Omega)$	Typical Total Capacitance C _T (pF)
3860	LO	0	Single	50	3.0/1.5*	0.20
3862	L2	2	Series			
3863	L3	3	Common Anode			
3864	L4	4	Common Cathode			
Test Conditions				V _R = V _{BR} Measure	I _F = 10 mA f = 100 MHz	$V_R = 50 \text{ V}$ $f = 1 \text{ MHz}$
				I _R ≤ 10 μA	*I _F = 100 mA	1 - 1 MHZ

Typical Parameters at T_A = $25\,^{\circ}C$

Part Number HSMP-	Series Resistance $R_S(\Omega)$	Carrier Lifetime τ (ns)	Reverse Recovery Time T _{rr} (ns)	Total Capacitance C _T (pF)
380X 381X 382X 383X 388X 389X	55 75 1.5 20 3.8 3.8	1800 1500 70* 500 2500 200*	500 300 7 80 550	0.32 @ 50 V 0.27 @ 50 V 0.60 @ 20 V 0.20 @ 50 V 0.30 @ 50 V 0.20 @ 5 V
Test Conditions	I _F = 1 mA f = 100 MHz I _F = 10 mA*	$I_{\rm F} = 50 \text{ mA}$ $I_{\rm R} = 250 \text{ mA}$ $I_{\rm F} = 10 \text{ mA*}$ $I_{\rm R} = 6 \text{ mA*}$	$V_R = 10 \text{ V}$ $I_F = 20 \text{ mA}$ 90% Recovery	

Note:

^{1.} Package marking code is white.

Typical Parameters at $T_A = 25$ °C (unless otherwise noted), Single Diode

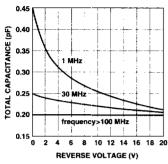


Figure 1. RF Capacitance vs. Reverse Bias, HSMP-3810 Series.

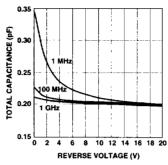


Figure 2. RF Capacitance vs. Reverse Bias, HSMP-3830 Series.

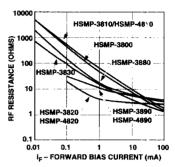


Figure 3. RF Resistance at 25°C vs. Forward Bias Current.

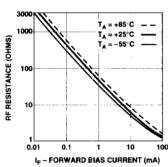


Figure 4. RF Resistance vs. Forward Bias Current for HSMP-3800.

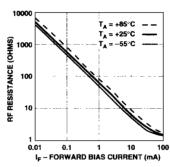


Figure 5. RF Resistance vs. Forward Bias Current for HSMP-3810/ HSMP-4810.

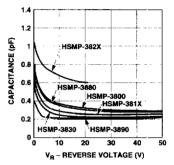


Figure 6. Capacitance vs. Reverse Voltage.

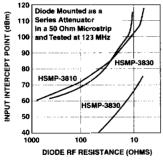


Figure 7. 2nd Harmonic Input Intercept Point vs. Diode RF Resistance for Attenuator Diodes.

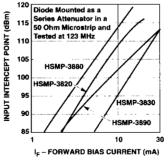


Figure 8. 2nd Harmonic Input Intercept Point vs. Forward Bias Current for Switch Diodes.

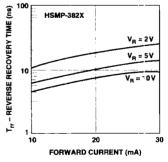


Figure 9. Reverse Recovery Time vs. Forward Current for Various Reverse Voltages. HSMP-3820 Series.

Typical Parameters (continued)

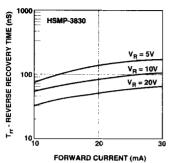


Figure 10. Reverse Recovery Time vs. Forward Current for Various Reverse Voltage. HSMP-3830 Series.

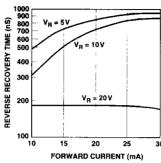


Figure 11. Typical Reverse Recovery Time vs. Reverse Voltage. HSMP-3880 Series.

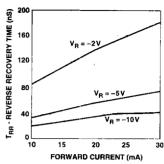


Figure 12. Typical Reverse Recovery Time vs. Reverse Voltage. HSMP-3890 Series.

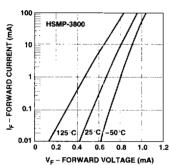


Figure 13. Forward Current vs. Forward Voltage. HSMP-3800 Series.

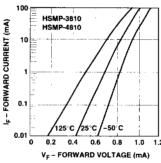


Figure 14. Forward Current vs. Forward Voltage. HSMP-3810 and HSMP-4810 Series.

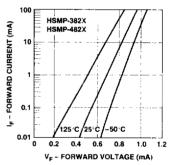


Figure 15. Forward Current vs. Forward Voltage. HSMP-3820 and HSMP-4820 Series.

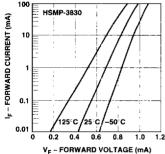


Figure 16. Forward Current vs. Forward Voltage. HSMP-3830 Series.

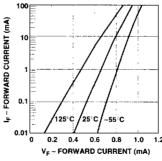


Figure 17. Forward Current vs. Forward Voltage. HSMP-3880 Series.

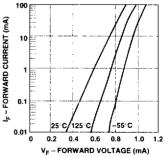


Figure 18. Forward Current vs. Forward Voltage. HSMP-3890 and HSMP-4890 Series.

Typical Parameters (continued)

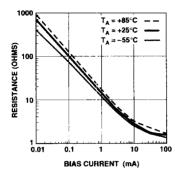


Figure 19. Typical RF Resistance vs. Forward Bias Current for HSMP-3860.

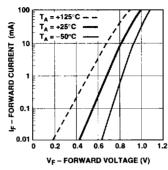


Figure 20. Forward Current vs. Forward Voltage for HSMP-3860.

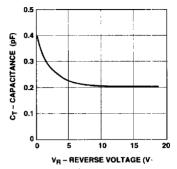
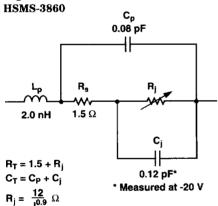


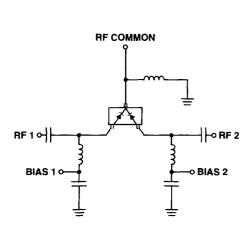
Figure 21. Typical Capacitance vs. Reverse Bias for HSMP-3860.

Equivalent Circuit Model



I = Forward Bias Current in mA

Typical Applications for Multiple Diode Products



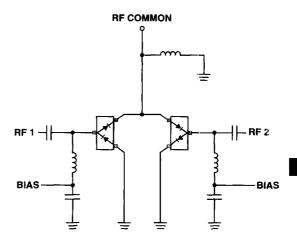
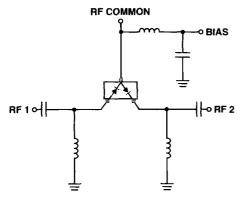


Figure 22. Simple SPDT Switch, Using Only Positive Current.

Figure 23. High Isolation SPDT Switch, Dual Bias.





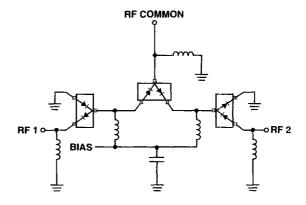


Figure 25. Very High Isolation SPDT Switch, Dual Bias.

Typical Applications for Multiple Diode Products (continued)

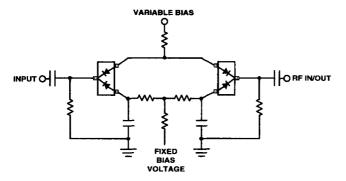


Figure 26. Four Diode π Attenuator.

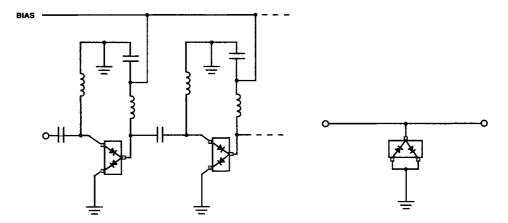


Figure 27. High Isolation SPST Switch (Repeat Cells as Required).

Figure 28. Power Limiter Using HSMP-3822 Diode Pair.

Typical Applications for HSMP-48XX Low Inductance Series



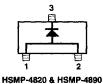


Figure 29. Internal Connections.

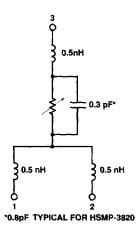


Figure 30. Equivalent Circuit.

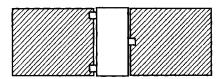


Figure 31. Circuit Layout.

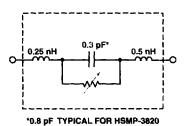


Figure 32. Equivalent Circuit.

Microstrip Series

Connection for HSMP-48XX Series

In order to take full advantage of the low inductance of the HSMP-48XX series when using them in series application, both lead 1 and lead 2 should be connected together, as shown above.



Figure 33. Circuit Layout.

Microstrip Shunt Connections for HSMP-48XX Series

In the diagram above, the center conductor of the microstrip line is interrupted and leads 1 and 2 of the

HSMP-38XX series diode are placed across the resulting gap. This forces the 0.5 nH lead inductance of leads 1 and 2 to appear as part of a low pass filter, reducing the shunt parasitic inductance and

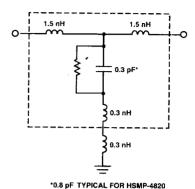


Figure 34. Equivalent Circuit.

increasing the maximum available attenuation. The 0.3 nH of shunt inductance external to the diode is created by the via holes, and is a good estimate for 0.032" thick material

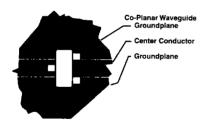


Figure 35. Circuit Layout.

Co-Planar Waveguide Shunt Connection for HSMP-48XX Series

Co-Planar waveguide, with ground on the top side of the printed circuit board, is shown in the diagram above. Since it eliminates the need for via holes to ground, it offers lower shunt parasitic inductance and higher maximum attenuation when compared to a microstrip circuit.

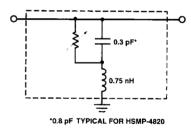
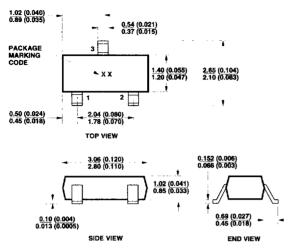


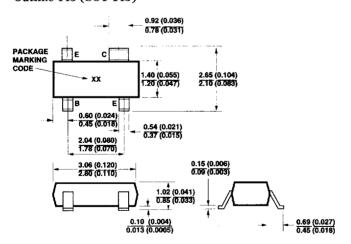
Figure 36. Equivalent Circuit.

Package Dimensions Outline 23 (SOT-23)



DIMENSIONS ARE IN MILLIMETERS (INCHES)

Outline 143 (SOT-143)

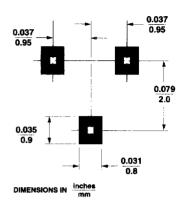


DIMENSIONS ARE IN MILLIMETERS (INCHES)

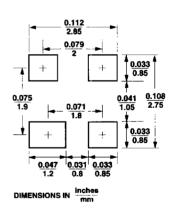
Package Characteristics

Lead Material	Alloy 42
Lead Finish	Tin-Lead 85-15%
Maximum Soldering Temperature	260°C for 5 seconds
Minimum Lead Strength	2 pounds pull
Typical Package Inductance	2 n H
Typical Package Capacitance	0.08 pF (opposite leads)

PC Board Footprints SOT-23



SOT-143



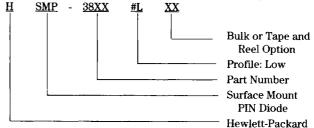
Ordering Information

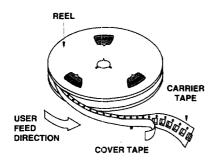
Option L30 = Bulk Option L31 = Tape and Reel, See Figures 37 and 38

Conforms to Electronic Industries RS-481, "Taping of Surface Mounted Components for Automated Placement." Standard Quantity is 3,000 Devices/Reel.

Ordering Information

Specify part number followed by option under. For example:





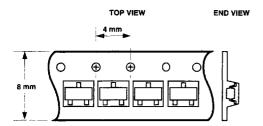


Figure 37. Option L31 for SOT-23 Packages.

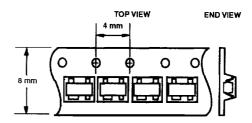


Figure 38. Option L31 for SOT-143 Packages.